

KAQV212G Series

6PIN 60V N.O TYPE
SOLID STATE RELAY-MOSFET OUTPUT

● Description

The KAQV212G series is robust, ideal for telecom and ground fault applications. It is a SPST normally open switch (1 Form A) that replaces electromechanical relays in many applications. It is constructed using a GaAlAs LED for actuation control and an integrated monolithic die for the switch output. The die, fabricated in a high-voltage dielectrically isolated technology, is comprised of a photodiode array, switch control circuitry and MOSFET switches.

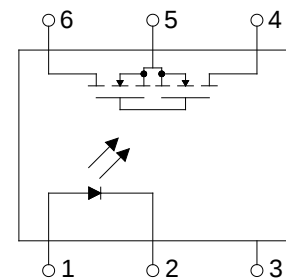
● Features

1. Normally open, single pole single throw
2. Control 60V AC or DC voltage
3. Switch 1.0A loads
4. Controls low-level analog signals
5. High sensitivity, low ON resistance
6. Low-level off-state leakage current
7. High isolation voltage 5KV (DIP / SMD)
8. Pb free and RoHS compliant
9. MSL class 1
10. Safety Approvals:
CQC GB4943.1-2022

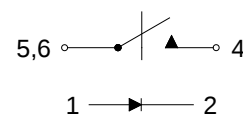
● Application

- Telecommunications (PC, electronic notepad)
- Modem
- Telephone equipment
- Security equipment
- Sensors
- Measuring and testing equipment
- Factory automation equipment
- High speed inspection machines

● Schematic



1 FORM A
NORMALLY OPEN



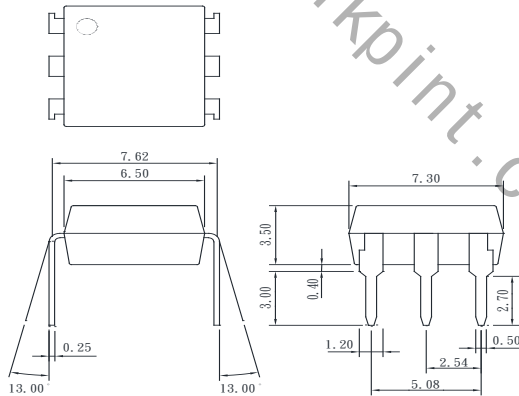
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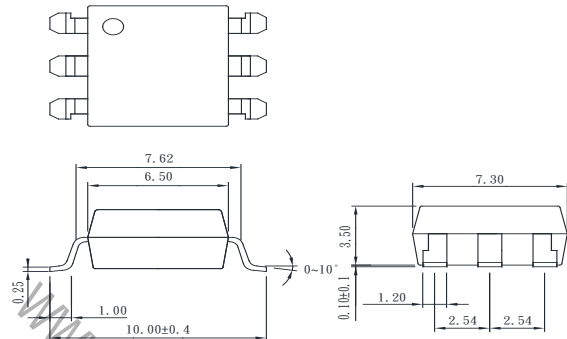
● Outside Dimension

Unit : mm

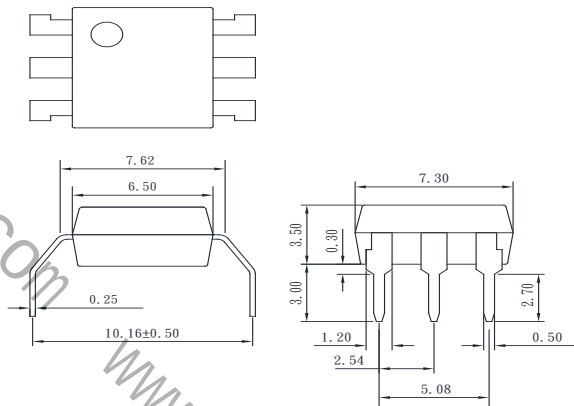
1. Dual-in-line type.



2. Surface mount type.

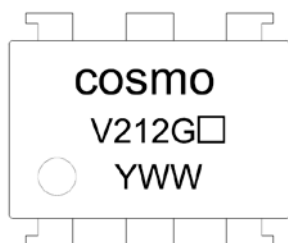


3. Long creepage distance type



TOLERANCE : ±0.2mm

● Device Marking



Notes :

cosmo
V212G
YWW

Part No.

Y : Year code / W : Week code

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● Absolute Maximum Ratings

(Ta=25°C)

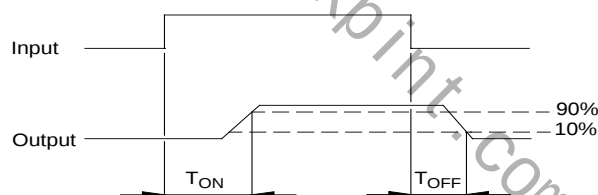
Parameter		Symbol	Rating	Unit
Input	Continuous forward current	I_F	50	mA
	Peak forward current	I_{FP}	1	A
	Reverse voltage	V_R	5	V
	Power dissipation	P_{in}	100	mW
	Derate linearly from 25°C	-	1.3	mW/°C
Output	Breakdown voltage	V_B	60	V
	Continuous load current	I_L	1	A
	Power dissipation	P_{out}	500	mW
Isolation voltage		V_{iso}	5000	Vrms
Isolation resistance ($V_{io}=500V$)		R_{iso}	$\geq 10^{10}$	Ω
Total power dissipation		P_t	550	mW
Derate linearly from 25°C		-	2.5m	mW/°C
Operating temperature		T_{opr}	-40 to +100	°C
Storage temperature		T_{stg}	-40 to +125	°C
Junction temperature		T_j	100	°C
Soldering temperature 10 seconds		T_{sot}	260	°C

● Electro-optical Characteristics

(Ta=25°C)

Parameter			Symbol	Conditions	Min.	Typ.	Max.	Unit
Input	Forward voltage		V_F	$I_F=10mA$	-	1.2	1.5	V
	Operation input current		I_{FON}	$V_L=20V, I_L=100mA$	-	-	3.0	mA
	Recovery input current		I_{FOFF}	$V_L=20V, I_L\leq 100\mu A$	0.2	-	-	mA
Output	Breakdown voltage		V_B	$I_B=100\mu A$	60	-	-	V
	Off-state leakage current		I_{LEAK}	$V_L=60V, I_F=0mA$	-	0.2	1.0	μA
I/O capacitance			C_{iso}	$V_B=0V, f=1MHz$	-	6	-	pF
ON resistance	connection	A	R_{ON}	$I_F=10mA, I_L=100mA$	-	0.25	0.7	Ω
		B			-	0.13	0.25	
		C			-	0.07	0.15	
Turn-on time			T_{ON}	$I_F=10mA, V_L=20V$	-	1.0	1.5	ms
Turn-off time			T_{OFF}	$I_L=100mA, t=10ms$	-	0.1	0.5	ms

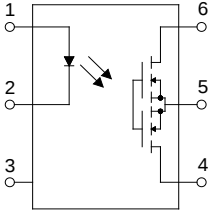
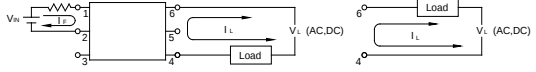
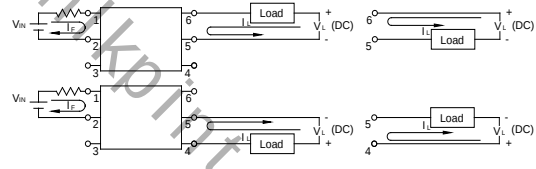
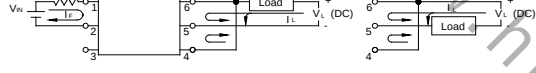
● Turn-on / Turn-off Time



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● Schematic and Wiring Diagrams

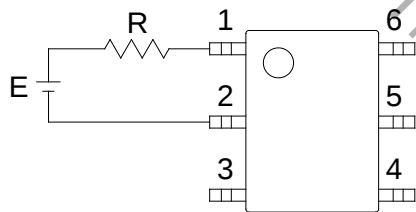
Schematic	Output Configuration	Load	Connection	Wiring Diagrams
	1a	AC DC	A	
		DC	B	
		DC	C	

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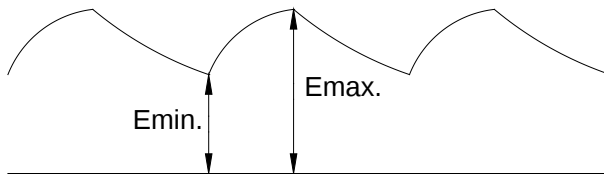
● Using Methods

Examples of resistance value to control LED forward current ($I_F=5\text{mA}$)

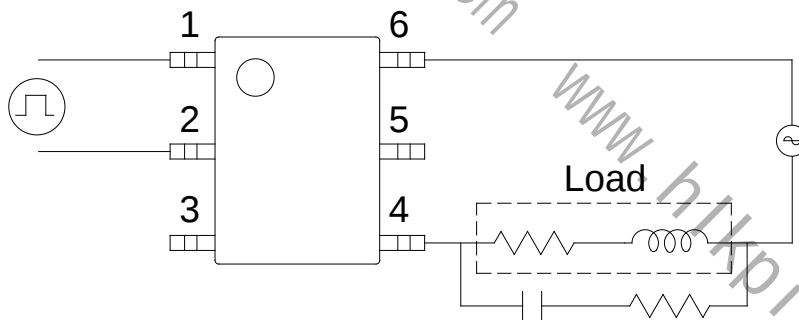
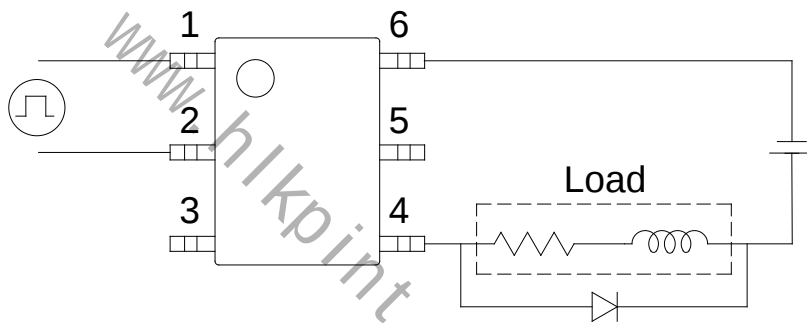


E	R
3.3V	Approx. 330 Ω
5V	Approx. 640 Ω
12V	Approx. 1.9K Ω
15V	Approx. 2.5K Ω
24V	Approx. 4.1K Ω

1. LED forward current must be more than 5mA , at E min.
2. LED forward current must be less than 50mA , at E max.



Regulate the spike voltage generated on the inductive load as follows :

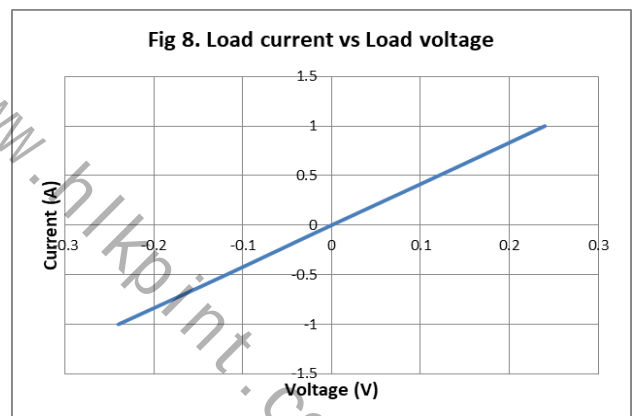
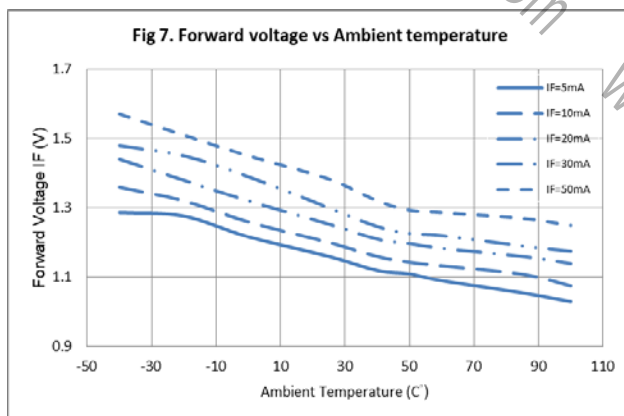
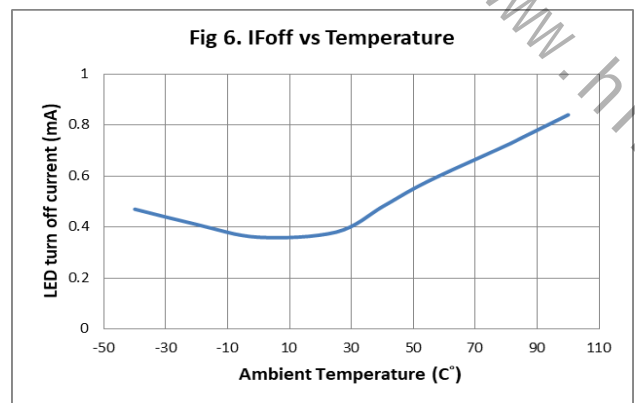
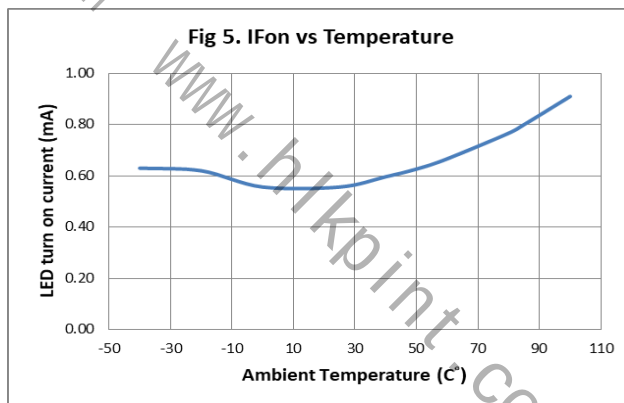
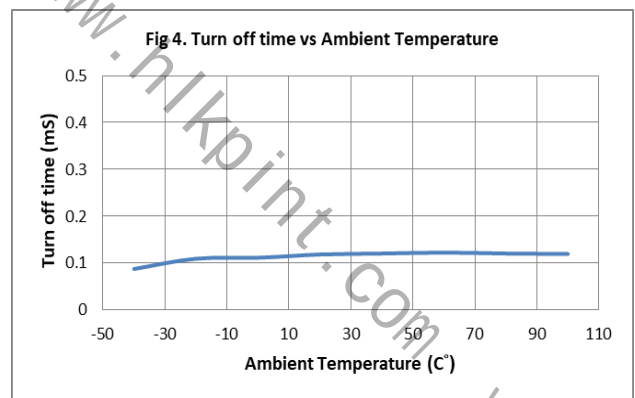
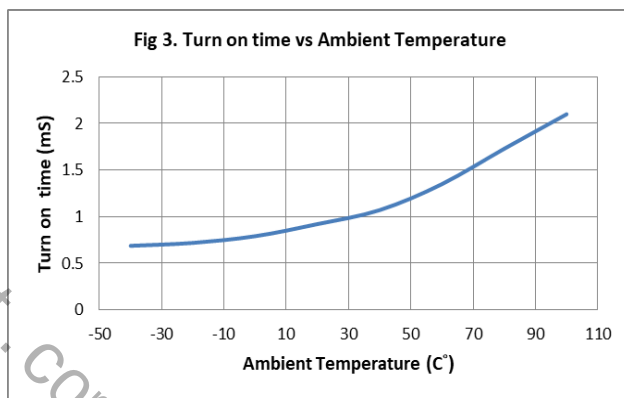
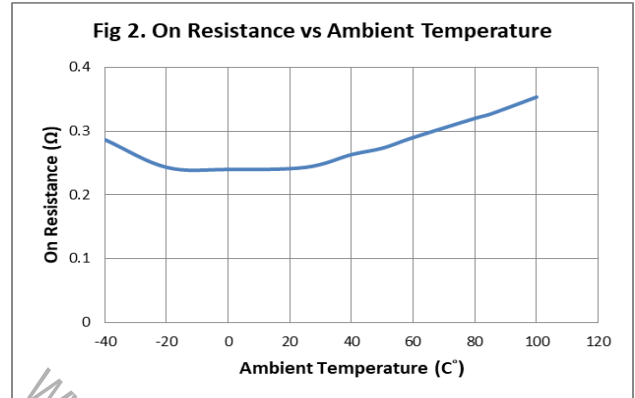
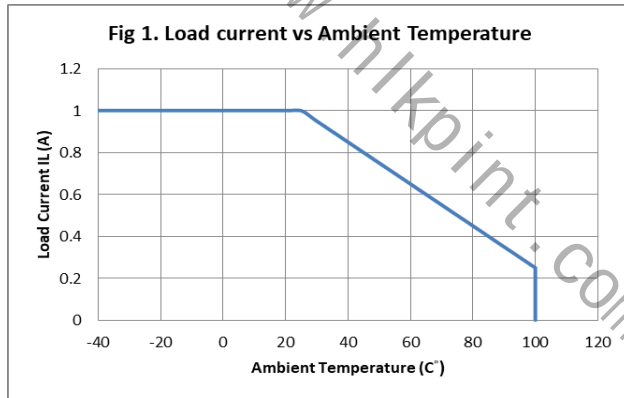


R-C Snubber

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Fig 9. Off state leakage current vs load current

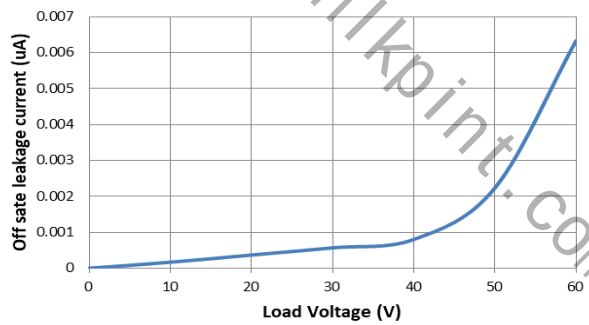


Fig 10. Turn on time vs IFon

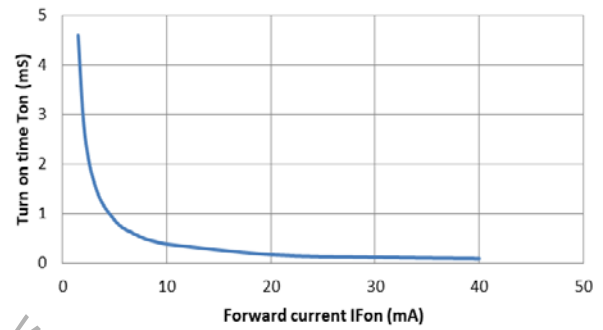
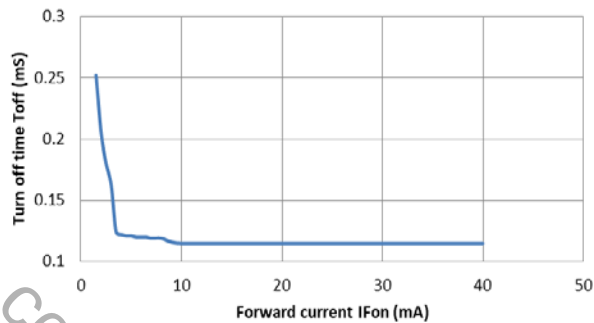


Fig 11. Turn off time vs IFon

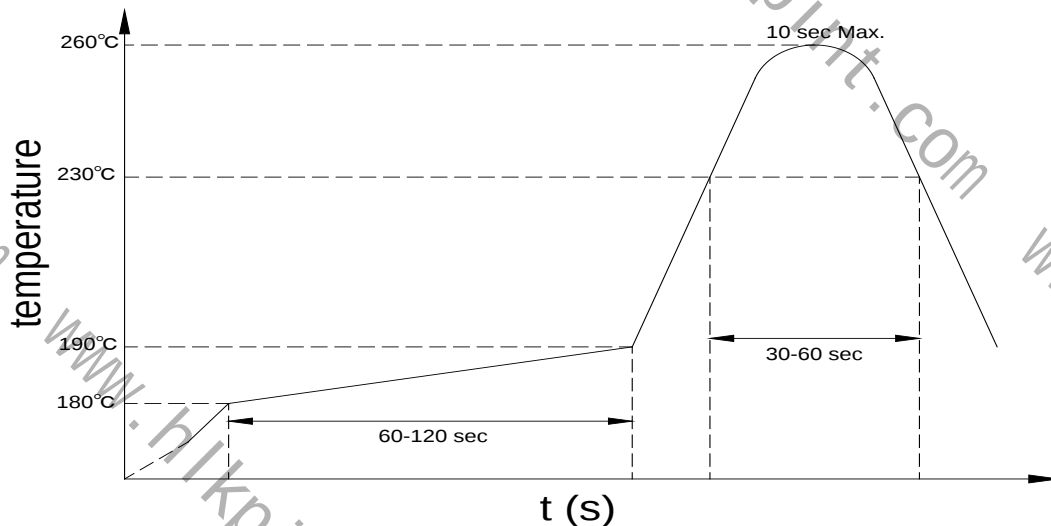


● **Recommended Soldering Conditions**

(a) Infrared reflow soldering :

- Peak reflow soldering : 260°C or below (package surface temperature)
- Time of peak reflow temperature: 10 sec
- Time of temperature higher than 230°C : 30-60 sec
- Time to preheat temperature from 180~190°C : 60-120 sec
- Number of reflows : Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)
- Flux :

Recommended Temperature Profile of Infrared Reflow



(b) Wave soldering :

- Temperature : 260°C or below (molten solder temperature)
- Time : 10 seconds or less
- Preheating conditions: 120°C or below (package surface temperature)
- Number of times : One
- Flux : Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(c) Cautions :

- Fluxes : Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.
- Avoid shorting between portion of frame and leads.

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- **Numbering System**

KAQV212G X (Y)

Notes:

KAQV212G = Part No.

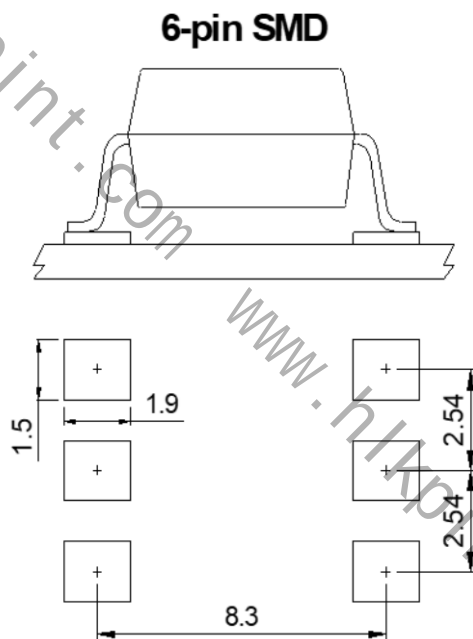
X = Lead form option (blank or A)

Y = Tape and reel option (TL 、 TR)

Option	Description	Packing quantity
A (TL)	surface mount type package + TL tape & reel option	1000 units per reel
A (TR)	surface mount type package + TR tape & reel option	1000 units per reel

- **Recommended Pad Layout for Surface Mount Lead Form**

1. Surface mount type.

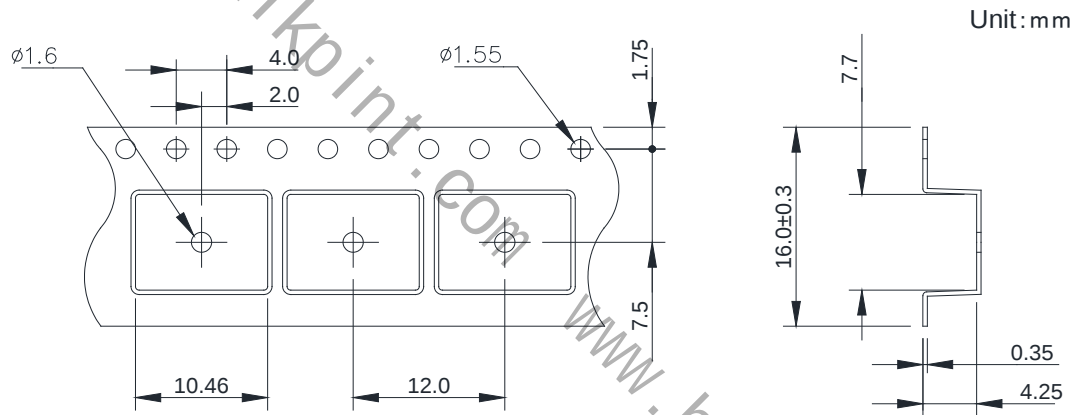


Unit : mm

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● 6-pin SMD Carrier Tape & Reel



TOLERANCE: ± 0.2 mm

